

L Number	Hits	Search Text	DB	Time stamp
1	10835	semiconductor and (ldd or (lightly adj doped adj drain))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/10/06 09:00
2	7181	(semiconductor and (ldd or (lightly adj doped adj drain))) and (gate adj electrode)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/10/06 09:00
3	535	((semiconductor and (ldd or (lightly adj doped adj drain))) and (gate adj electrode)) and (taper\$3)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2002/10/06 09:04